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PEN	Application		Filing Da		Examine	
N 27 2001	<u> </u>		April 22, 1999		E. Kielin	2813
1 .	Invention: FABRICATION OF DRAM AND OTHER SEMICONDUCTOR DEVICE INSULATING FILM USING A WET RAPID THERMAL OXIDATION P TO THE COMMISSIONER FOR PATENTS Transmitted herewith is an amendment in the above-identified application. The fee has been calculated and is transmitted as shown below.					
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			CLAIM	S AS AMEN	IDED	
		Claims Remaining After Amendment	Highest Number Previously Paid	Number Extra Claims Present	Rate	
	Total Claims	37	- 37 =		×	0.00
	Independent Claims	5	- 5 =		×	0.00
	Multiple Dependent Claims (check if applicable)					
	Other fee (please specify): TOTAL ADDITIONAL FEE FOR THIS AMENDMENT:					0.00
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	x No additiona	al fee is require	d for this ame	ndment.		
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	A check in the	ne amount of \$		to cover	r the filing fee is e	enclosed.
			t of \$ to cover the filing fee is enclosed. hereby authorized to charge and credit Deposit Account No04-1073 A duplicate copy of this sheet is enclosed.			
	x Credit any overpayment.					
	x Charge a	any additional fil	ing or application	on processing	fees required und	er 37 CFR 1.16 and 1.17.
	Thomas J. D'Af Attorney Reg. N				Dated:	November 27, 2001
	DICKSTEIN SH 2101 L Street N Washington, D (202) 828-2232	HAPIRO MORI NW C 20037-1526		Y LLP		
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Docket Nov. M4065.0319/P319 /2/

HE UNITED STATES PATENT AND TRADEMARK OFFICE OF MAIL O

In re Patent Application of: Ronald A. Weimer, et al.

Application No.: 09/296,835

Group Art Unit: 2813

Filed: April 22, 1999

Examiner: E. Kielin

For: FABRICATION OF DRAM AND OTHER

SEMICONDUCTOR DEVICES WITH AN

INSULATING FILM USING A WET

RAPID THERMAL OXIDATION PROCESS

<u>AMENDMENT</u>

Box Non-Fee Amendment

Commissioner for Patents Washington, DC 20231

Dear Sir:

In response to the Office Action dated August 28, 2001 (Paper No. 19), please amend the above-identified U.S. Patent application as follows:

In the Claims:

Please amend independent claim 8 and dependent claims 5 and 6 as shown in the Replacement Claims: